

## SiC SCHOTTKY DIODE TYPE 2×140A

### Features

- High surge current capable
- Zero reverse recovery current
- High bandwidth
- Isolation type package
- Temperature Independent Switching Behavior
- VDC 650 V
- $I_F$  ( $T_C < 135^\circ\text{C}$ ) 2×140 A

### Benefits

- Unipolar rectifier
- Zero switching loss
- Higher efficiency
- Smaller heat sink
- Parallel devices without thermal runaway

### Applications

- Motor drives
- Switch mode power supplies
- Ev chargers
- Solar inverters
- Welding equipment
- Power factor correction
- Diode snubber
- Automotive
- induction heating

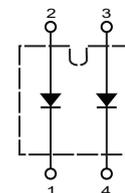
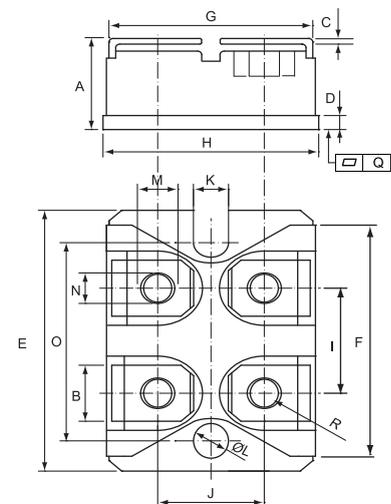
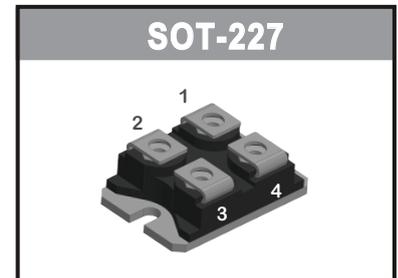
### Maximum Ratings

Operating Junction Temperature :  $-55^\circ\text{C}$  to  $+175^\circ\text{C}$

Storage Temperature :  $-55^\circ\text{C}$  to  $+175^\circ\text{C}$

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI2×140-065P3B	650V	650V

Maximum Rating	Symbol	Conditions	Value	Unit
Continuous forward current (per diode)	$I_F$	$T_C = 135^\circ\text{C}$	140	A
Surge non-repetitive forward current sine halfwave (per diode)	$I_{FSM}$	$T_C = 25^\circ\text{C}$ , $t_p = 8.3\text{ ms}$	1000	
		$T_C = 150^\circ\text{C}$ , $t_p = 8.3\text{ ms}$	700	
Non-repetitive peak forward current (per diode)	$I_{F,max}$	$T_C = 25^\circ\text{C}$ , $t_p = 10\ \mu\text{s}$	4200	
		$T_C = 150^\circ\text{C}$ , $t_p = 10\ \mu\text{s}$	2600	
Repetitive peak reverse voltage	$V_{RRM}$	$T_J = 25^\circ\text{C}$	650	V
Isolation voltage between All Terminals and Baseplate	$V_{iso}$	50/60 Hz, $t = 1\text{min}$ $I_{ISOL} \leq 1\text{mA}$	2500	V
Mounting torque		To heatsink	1.3	Nm
		To terminal	1.1	



parallel

	DIMENSIONS			
	INCHES		MM	
	MIN	MAX	MIN	MAX
A	0.460	0.483	11.68	12.28
B	0.307	0.323	7.80	8.20
C	0.030	0.033	0.75	0.85
D	0.071	0.081	1.80	2.05
E	1.488	1.504	37.80	38.20
F	1.248	1.260	31.70	32.00
G	0.917	0.957	23.30	24.30
H	0.996	1.008	25.30	25.60
I	0.579	0.602	14.70	15.30
J	0.492	0.516	12.50	13.10
K	0.161	0.169	4.10	4.30
L	0.161	0.169	4.10	4.30
M	0.181	0.197	4.60	5.00
N	0.165	0.181	4.20	4.60
O	1.181	1.197	30.00	30.40
Q	-0.002	0.004	-0.05	0.10
R	M4*8			

**Electrical Characteristics**, at  $T_j=25\text{ }^\circ\text{C}$ , unless otherwise specified. (per diode)

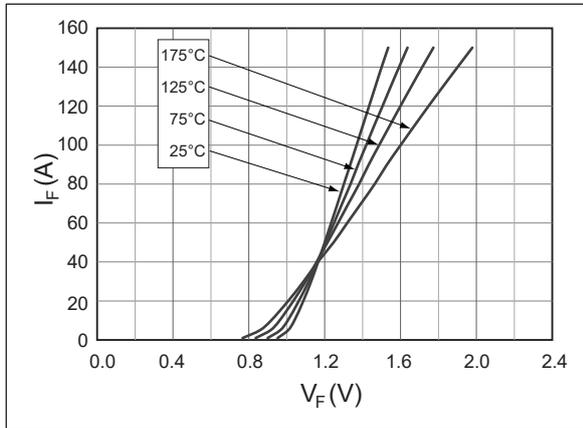
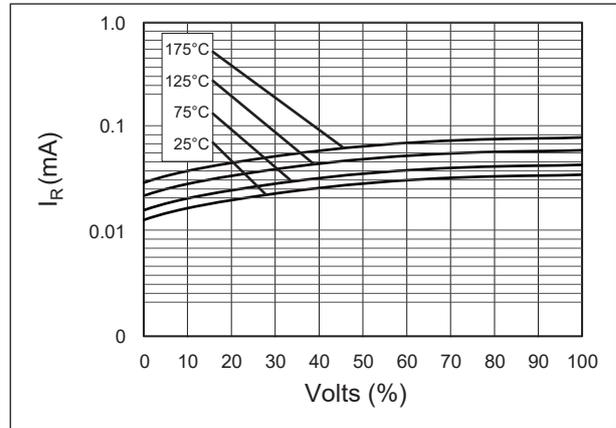
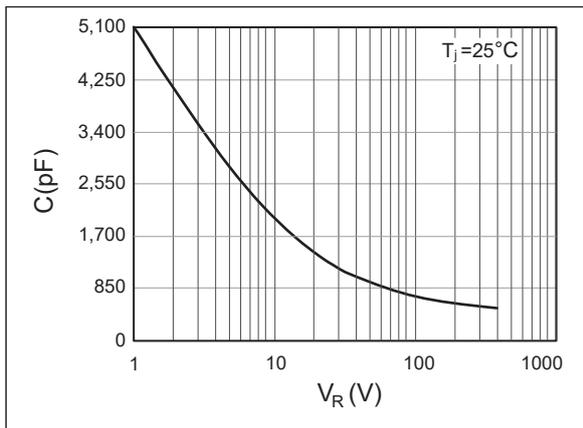
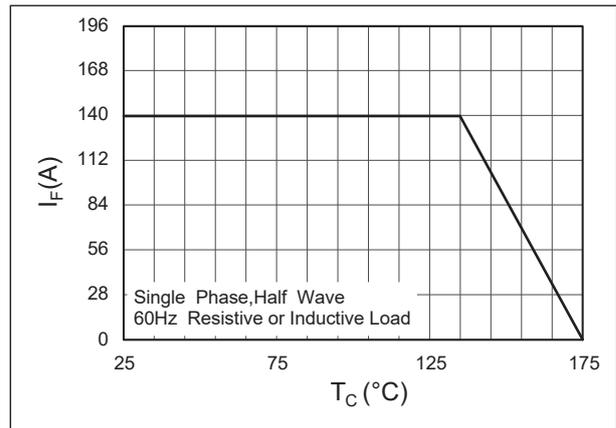
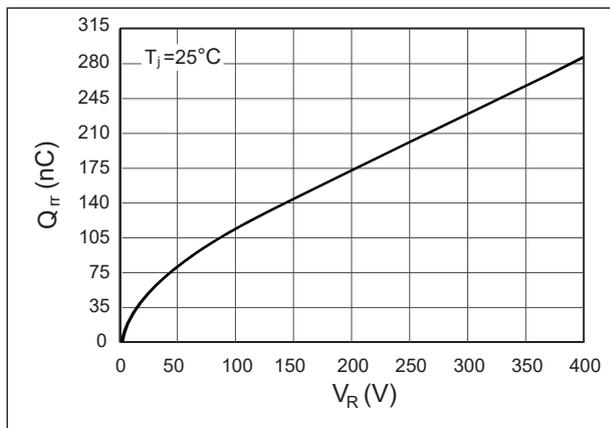
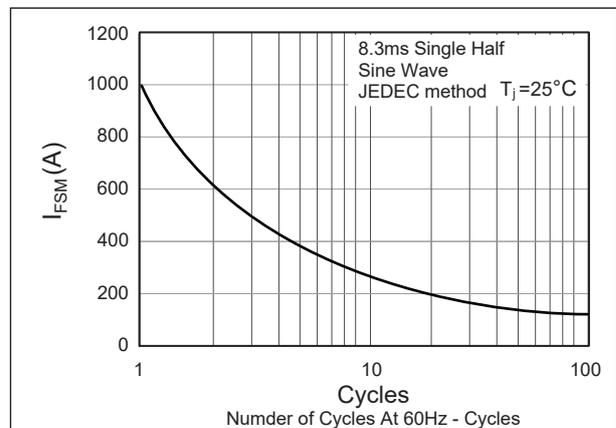
Static Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
DC blocking voltage	$V_{DC}$		650	-	-	V
Diode forward voltage	$V_F$	$I_F=100\text{A}, T_j=25\text{ }^\circ\text{C}$	-	1.5	1.7	
		$I_F=100\text{A}, T_j=175\text{ }^\circ\text{C}$	-	1.9	2.2	
Reverse current	$I_R$	$V_R=650\text{V}, T_j=25\text{ }^\circ\text{C}$	-	50	100	$\mu\text{A}$
		$V_R=650\text{V}, T_j=175\text{ }^\circ\text{C}$	-	100	500	

**AC Characteristics** (per diode)

Static Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
Total capacitive charge	$Q_{rr}$	$V_R=400\text{V}, T_j=25\text{ }^\circ\text{C}$	-	282	-	nC
Total capacitance	C	$V_R=1\text{V}, f=1\text{ MHz}$ $T_j=25\text{ }^\circ\text{C}$	-	5055	-	pF
		$V_R=200\text{V}, f=1\text{ MHz}$ $T_j=25\text{ }^\circ\text{C}$	-	565	-	
		$V_R=400\text{V}, f=1\text{ MHz}$ $T_j=25\text{ }^\circ\text{C}$	-	440	-	

**Thermal Characteristics** (per diode)

Static Characteristics	Symbol	Values	Unit
		typ.	
Thermal resistance from junction to case	$R_{\theta JC}$	0.14	$^\circ\text{C/W}$

**Typical Performance**
**Forward Characteristics** (parameterized on  $T_j$ )

**Reverse Characteristics** (parameterized on  $T_j$ )

**Capacitance**

**Current Derating**

**Recovery Charge**

**Forward Surge Current**


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